

Superballistic flow of viscous electron fluid induced by microwave
irradiation in quantum point contact

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Abstract

We measure the resistance oscillation of quantum point contact (QPC) under microwave (MW) radiation. What is different from the common resistance oscillation induced by edge magnetoplasmon (EMP) is that at lower magnetic field ($\omega > \omega_c$), photoconductance is positive (negative) with weak (strong) MW radiation. This transport phenomenon is proved to be related to superballistic flow of electrons through QPC. The distinction between the regions $\omega > \omega_c$ and $\omega < \omega_c$ is attributed to different absorption rate of MW radiation. Violent absorption occurs when cyclotron orbits or current domains are destroyed in QPC region.

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Introduction. - Hydrodynamic charge transport in high-mobility two dimensional electron gas (2DEG) has aroused much attention since viscosity of electron was verified in electron systems, e.g., graphene [1,2] and GaAs/AlGaAs quantum well (QW) [3-9]. Hydrodynamic regime induced by collective motion of electrons is reached when momentum conserving collisions between electrons dominate, which corresponds to the condition that mean free path (MFP) of electron-electron collision l_{ee} is much shorter than both sample width W and MFP of electron-impurity/phonon collision l_0 . There are some prominent phenomena relevant to hydrodynamic charge transport, e.g., superballistic flow through narrow constrictions [2], negative resistance resulting from whirlpools of electron flow [8] and negative magnetoresistance (NMR) of Poiseuille flow [9,10]. Superballistic transport is the most interesting and counterintuitive phenomenon among them [2]. Narrow constriction in 2DEG forms a quantum point contact (QPC) and it has a quantum conductance decided by channel number N_{QPC} multiply $2e^2/h$ for ballistic transport [11,12]. Interestingly, collective movement of viscous electrons can shield carriers from momentum loss at sample edges, thus resulting in larger QPC conductance.

In our previous work [9], hydrodynamic charge transport under microwave (MW) radiation in ultrahigh-mobility GaAs/AlGaAs 2DEG is studied through size dependence of second harmonic peak [10] and microwave-induced resistance oscillation (MIRO) [13-16]. For wide samples, i.e., $W \gg v_F \tau_2$ (v_F is Fermi velocity and τ_2 is the relaxation time of the second moment of electron distribution function), theories [17-22] predicted that MIRO amplitude is linear with W . For narrow samples, i.e., $W \ll v_F \tau_2$, MIRO is too weak to be detected. Naively thinking, there should be nothing interesting when sample width decreases to microns or submicron.

Surprisingly, we find out that there is another kind of resistance oscillation for QPCs under MW radiation. It is induced by interference of edge magnetoplasmon (EMP) [23-27] and severely relies on MW power P_{MW} . Under strong MW radiation, resistance oscillation shows huge and violent resistance peaks. While under weak MW radiation, resistance maximum astonishingly turns into resistance minimum, which is a sign of superballistic transport. Considering size dependence of radiation heating effect

[9], we eventually reach a conclusion that QPC is extremely hot when strong MW absorption happens, with electron temperature T_e even around $100 K$ while ambient temperature T_b is about $2K$.

The reason for the great MW absorption in QPC is very intriguing and is still an open question. It seems to be related to MIRO or zero-resistance state (ZRS). For high mobility 2DEG, some low-order minima of MIRO cannot form negative resistance but transform to ZRS [15,16,28], because homogeneous state with negative resistivity is electrically unstable and naturally breaks into current domains [29-32]. We find that resistance minima/maxima of the novel resistance oscillation appear only when bulk 2DEG is in the regime of MW induced ZRS. This is not a coincidence because narrow constriction like QPC can break down current domain of ZRS.

Experimental setup. - Our experiment is performed in a ^3He refrigerator (base temperature $T_b = 0.3K$) with two wafers. After being illuminated by red light-emitting diode at $2K$, one is high-mobility 2DEG with μ around $2 \times 10^6 \text{cm}^2/\text{Vs}$ and the other has better quality with μ above $2 \times 10^7 \text{cm}^2/\text{Vs}$ at $0.3K$. Carrier density n is both around $2.6 \times 10^{11} \text{cm}^{-2}$. Each sample consists of several QPCs with different constriction widths W from $3.2\mu\text{m}$ to $0.2\mu\text{m}$. We use two kinds of QPCs. One is normal split gate QPC defined by e-beam lithography and Ti/Au top gate, and the other is constricted by wet etching without metal gate. Electrical contacts are made by Ge/Pd/Au alloy annealed at 450°C . For details of each sample, please refer to Table SI of [33]. In our experiment, MW with frequency f ranging from 30GHz to 105GHz is generated by Gunn oscillators and MW power P_{MW} is adjusted by a programmable rotary vane attenuator. Resistance is measured with low-frequency lock-in technique.

We measure the longitudinal resistance R_L through each QPC for the sake of symmetry of magnetoresistance (Fig.1(a)). According to Landauer-Buttiker formula [34],

$$R_L = \frac{h}{2e^2} \frac{1}{N_{QPC}} - |R_{xy}|, \quad (1)$$

Since Hall resistance R_{xy} is not affected by MW radiation, the measured response of R_L to MW fully reflects that of QPC resistance R_{QPC} . Effective width W of QPC is decided by Sharvin formula,

$$R_b = \frac{h}{2e^2} \frac{\sqrt{\pi}}{W\sqrt{2n}}, \quad (2)$$

where the ballistic resistance $R_b = h/(2e^2 N_{QPC})$ is the measured value of R_{QPC} in zero magnetic field without MW. Under MW radiation, R_{QPC} deviates from R_b and we can measure its value in the following method. Since MW has little influence on R_{xy} , we obtain that $R_{QPC,MW} = R_{L,MW} + |R_{xy}| = R_{L,MW} - R_{L,0} + R_b$. Here, $R_{QPC,MW}$, $R_{L,MW}$ and $R_{L,0}$ denotes the resistance with or without MW radiation respectively.

Considering the fact that R_L is mixed with R_{xx} in the measurement, we note that $R_{L,MW}$ also incorporates MIRO signal in the bulk 2DEG. Due to high mobility of our samples, the mixed R_{xx} is only several Ohms and does not influence the measured value of R_{QPC} .

Characteristics of the novel resistance oscillation. - Fig.1(b) shows overall feature of the novel resistance oscillation. There are two regions split apart by cyclotron resonance $\omega = 2\pi f = \omega_c$, where $\omega_c = eB/m^*$, $m^* = 0.067m_e$ is effective mass of electron in GaAs QW, B is magnetic field. Before introducing the novel resistance oscillation, we first notice that B-periodic oscillation in the high field region ($\omega < \omega_c$) is unambiguously attributed to EMP [23-27]. EMPs excited by MW propagate along the sample edge and interfere with each other in the QPC. The oscillation period of EMP satisfies $\Delta B \propto 1/\omega$, which is verified in our samples [23].

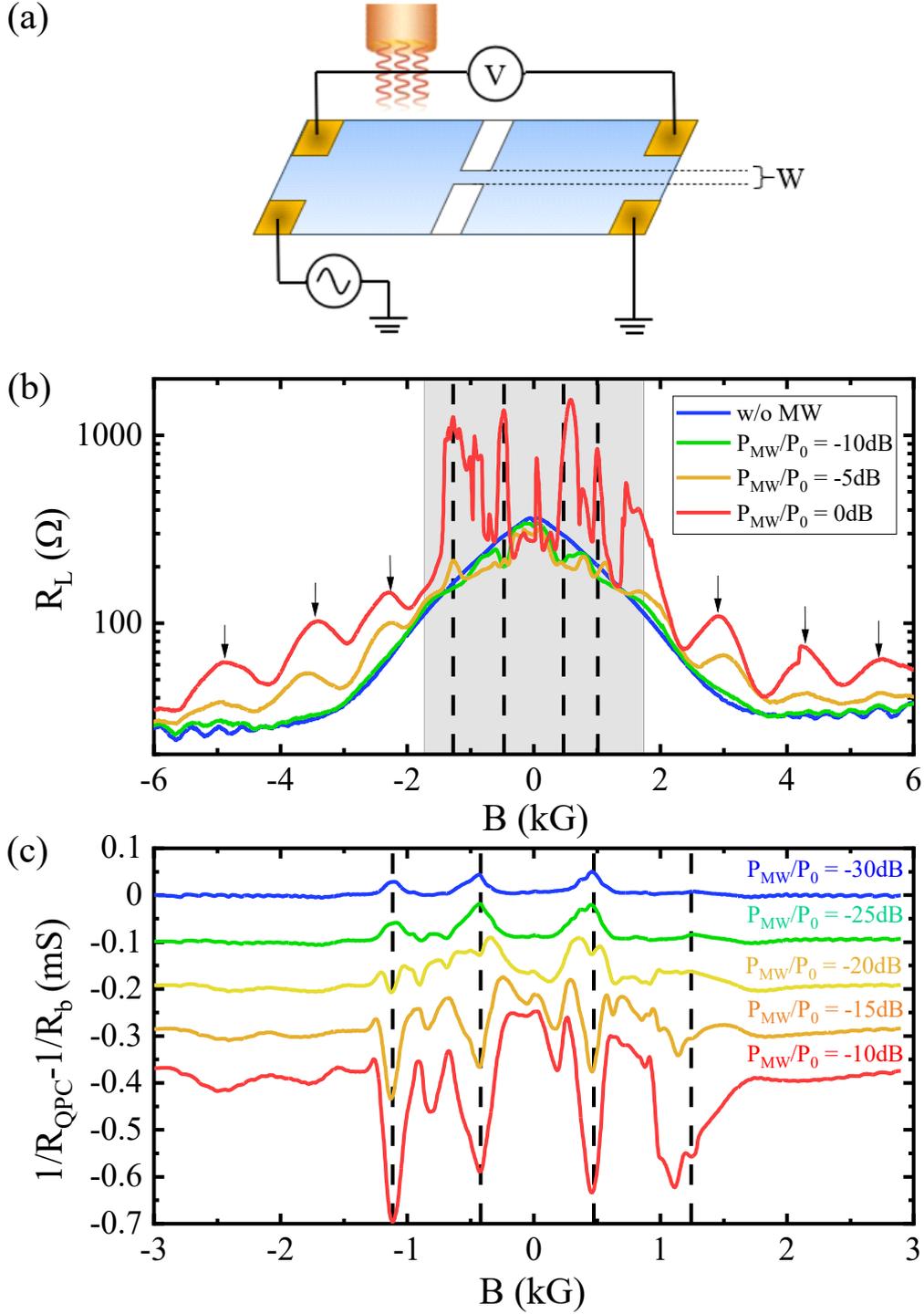


FIG. 1. (a) General setup of resistance measurement: a QPC with width W under MW irradiation can bring about peculiar photoconductance. (b) The longitudinal resistance shows EMP-induced resistance oscillation and there is a crossover at $\omega = \omega_c$. In high magnetic field, the oscillation is B -periodic (arrows), while at $\omega > \omega_c$ (grey background) positive-to-negative photoconductance pattern and strange behavior of oscillations appear. Dash lines indicate positions of resistance minima/maxima. The

attenuation P_{MW}/P_0 ranges from $-10dB$ to $0dB$. Background temperature T_b is kept at $3K$. MW frequency f is $71GHz$. This result is from QPC 1b, which is a split gate one with effective width W around $0.9\mu m$ and gate voltage $V_{QPC} = -2.2V$. (c) Positive-to-negative photoconductance transformation (dash lines) happens when P_{MW}/P_0 is set from $-30dB$ to $-10dB$. Photoconductance for different MW power is consecutively shifted downward by $0.1mS$. The data is from QPC 2d, an etched one with effective width W around $0.2\mu m$ at $T_b = 0.3K$.

More interesting region is in low magnetic field ($\omega > \omega_c$), where periodicity of the resistance oscillation seems elusive. For the example in Fig.1(b), when P_{MW} is $-10dB$ multiplying power of Gunn oscillator P_0 , photo-induced resistance $R_{L,MW} - R_{L,0}$ is negative at some magnetic field (positive photoconductance). When $P_{MW}/P_0 = 0dB$, dips of R_{QPC} magically develop into huge peaks whose resistance is much larger than those at $\omega < \omega_c$ and multiple times of R_L without MW (negative photoconductance). Similar phenomena appear in both split gate and etched QPCs, both high- and ultrahigh-mobility samples as well. For clarity, photoconductance $1/R_{QPC,MW} - 1/R_b$ is calculated for the data of another QPC (Fig.1(c)). The positive-to-negative photoconductance transformation is main feature of $\omega > \omega_c$ region.

In our previous work [23], we studied the EMP-induced resistance oscillation in relatively low-mobility samples and we did not focus on the positive-to-negative photoconductance transformation because it is more obvious for ultrahigh-mobility samples. According to paper [23], the peculiar resistance oscillation in our ultrahigh-mobility samples also comes from interference of EMPs. At interference construction point of EMPs, electrons sufficiently absorb MW irradiation, which brings about huge photoconductance. While at interference destruction point, QPC resistance R_L is hardly influenced by MW. The data of ultrahigh-mobility sample is more interesting because of good quality of 2DEG and important role played by hydrodynamic transport.

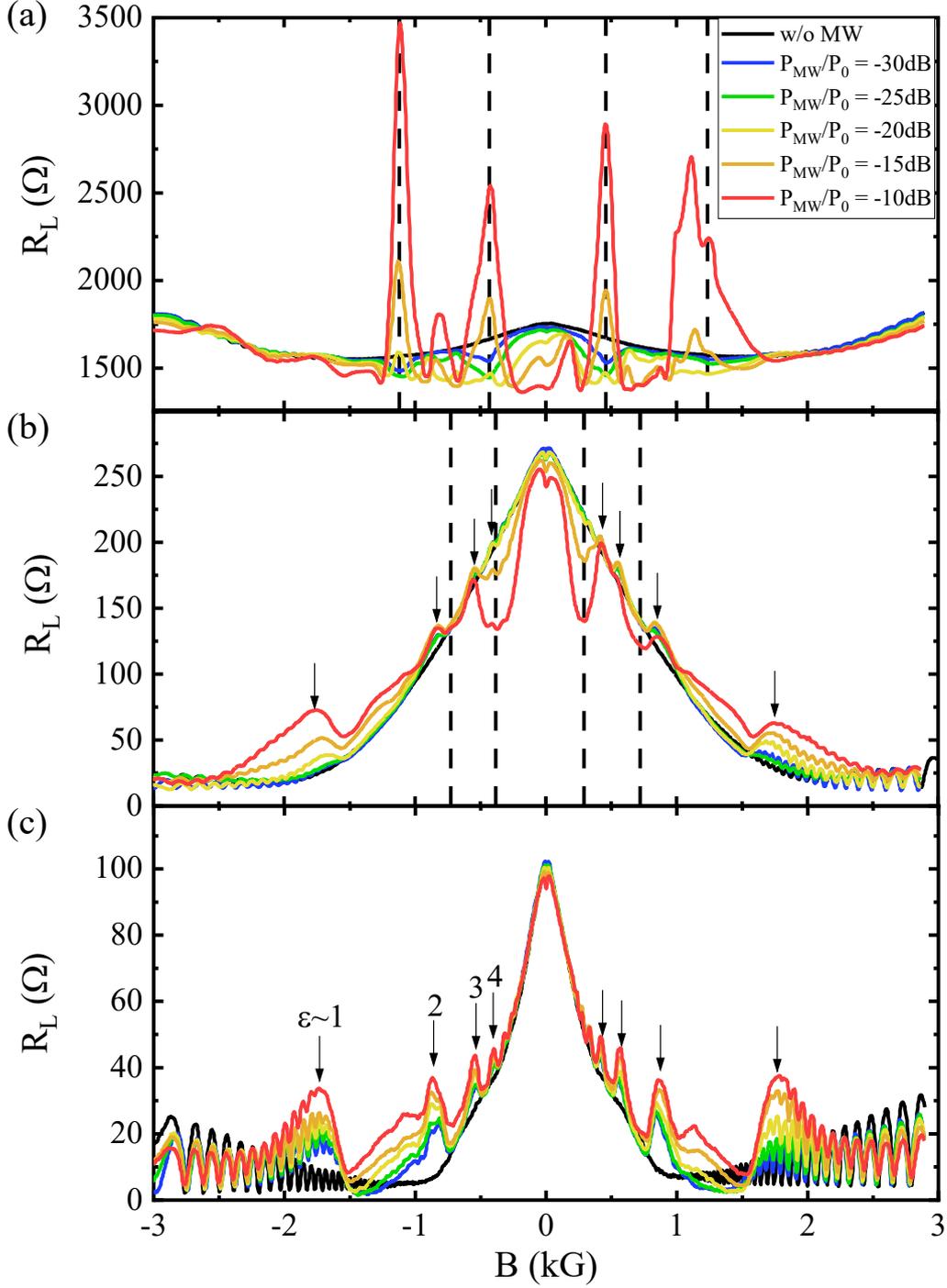


FIG. 2. The EMP-induced resistance oscillation in different QPCs under MW radiation with variant power together with bulk MIRO signal is shown: (a) QPC 2d, $W = 0.2\mu\text{m}$, (b) QPC 1a, $W = 1.2\mu\text{m}$, (c) QPC 2a, $W = 3.2\mu\text{m}$. Attenuation P_{MW}/P_0 ranges from -30dB to -10dB . Arrows indicate observable low-order maxima of MIRO and dash lines mark the positions of resistance minima/maxima induced by EMPs. T_b is kept at 0.3K and MW frequency f remains 71GHz .

Size dependence of the MW-induced resistance oscillation in QPC is demonstrated in Fig.2. For the narrowest QPC with $W = 0.2\mu m$ (Fig.2(a)), even very weak MW ($P_{MW}/P_0 < -30dB$) can result in resistance minima and they develop into maxima at $P_{MW}/P_0 = -15dB$. For QPC 1a with $W = 1.2\mu m$ (Fig.2(b)), MIRO appears in the background of NMR and the resistance minima do not turn into peaks until $P_{MW}/P_0 > -10dB$. Compared with QPC 2d, photoconductance $1/R_{QPC,MW} - 1/R_b$ of resistance minima in this wide QPC enhances dramatically. Photoconductance of QPC 2d is of the order of $0.1mS$ while that of QPC 1a is around $1mS$. For the widest constriction (Fig.2(c)), EMP-induced resistance oscillation doesn't appear but MIRO does. This indicates that the EMP-induced resistance oscillation only occurs in narrow QPCs. We arrive at a conclusion that wider QPC needs stronger MW to show the oscillation; but once there is EMP-induced resistance decrease, its photoconductance is much larger than the narrower one.

Superballistic model. - Strange pattern of the resistance oscillation at $\omega > \omega_c$ is hard to explain unless viscosity of electrons is considered. We notice that the positive-to-negative pattern of resistance variance frequently occurs in hydrodynamic electron systems, where electron-electron interaction plays an important role. An unusual decrease of QPC resistance with temperature was reported in previous work [35] and it was explained as electron-electron interactions mediated by boundaries. More recently, superballistic flow of viscous charge is studied in graphene constrictions [2]. QPC resistance first decreases and then increases as temperature goes higher. The former is attributed to interacting electrons shielding the momentum loss caused by boundaries and the latter is due to decrease of l_0 . Viscosity of electrons modifies quantum conductance $G_b = 1/R_b$ to be $G_b + G_v$ and the viscosity contribution

$$G_v = \frac{\sqrt{2\pi n} e^2 W^2}{16\hbar v_F \tau_2}, \quad (3)$$

where \hbar is Planck constant divided by 2π . G_v is calculated for the Stokes flow through a QPC in both hydrodynamic and ballistic regime [36]. This description is valid

when phonon scattering does not dominate.

It is reasonable to think that the positive-to-negative photoconductance transformation is related to superballistic effect, for our samples are 2DEG of great quality where viscous electrons form collective flow at certain temperature. MW, absorbed by electrons passing through QPC, can significantly heat up the carriers in narrow constrictions, while electrons in the bulk remains cold. It makes sense since under strong MW radiation, T_e of electrons in narrow constrictions is much higher than that in the bulk, and the latter is much higher than T_b [9]. We are going to demonstrate that resistance of the minima/maxima in our experiment depends on MW power in the same pattern as resistance of superballistic electron flow depends on temperature.

Size dependence of the MW power sensitivity demonstrated in Fig.2 can be explained by size dependence of radiation heating effect [9]. Because of its lower conductance, narrower QPC absorbs more MW and its electrons are hotter. As a result, narrower QPC exhibits superballistic effect with weaker MW. Although narrow QPC response to MW sensitively, its photoconductance variance in hydrodynamic regime is small.

Size dependence of the photoconductance increase follows the rule of hydrodynamic transport. Maximum photoconductance of resistance minima $G_{v,max} = (1/R_{L,MW} - 1/R_{L,0})_{max}$ under different MW power P_{MW} is approximately proportional to W^2 (Fig.3(a)), which is exactly the same as superballistic transport in QPCs. The W^2 size dependence of photoconductance originates from viscous fluid self-organizing into streams with variant velocities in Poiseuille regimes.

Since viscous relaxation time τ_2 can be extracted from the full width half maximum of NMR in 2DEG [17], we fit $1/\tau_2$ with T_e with the following equation [21],

$$\frac{1}{\tau_2} \propto \frac{T_e^2}{\ln^2(\epsilon_F/k_B T_e)}, \quad (4)$$

where ϵ_F is Fermi energy and k_B is Boltzmann constant. Combining Eq.(3) and (4), we can then extract T_e from R_{QPC} in each resistance dip, assuming that electrons in

QPC are still in hydrodynamic regime. We plot the extracted T_e of four QPCs in Fig.3(b). T_e is much higher than $T_b = 0.3K$ and positively related to P_{MW} . When T_e is larger than $15K$, phonon scattering begins to dominate and the temperature extracted is lower than its real value. Saturation of calculated T_e happens at about $15K$ for all the four QPCs (and the actual temperature after phonon scattering considered is higher, around $20 \sim 30K$ according to Fig.3(c) [33]), implying the crossover between superballistic and phonon scattering regime for GaAs 2DEG. Furthermore, we can fix the absorbed MW power $P_{a,MW}$ of all the QPCs to be the same value by simple translation of P_{MW} axis for each QPC. T_e only relies on $P_{a,MW}$ and MW absorption rate $P_{a,MW}/P_{MW}$ is size dependent [9]. Fig.3(c) shows the uniform relation between T_e and $P_{a,MW}$. Assuming that actual T_e is power function of $P_{a,MW}$, we make a logarithmic fit of our low temperature data which is not affected by phonon scattering, and extrapolate T_e to larger P_{MW} .

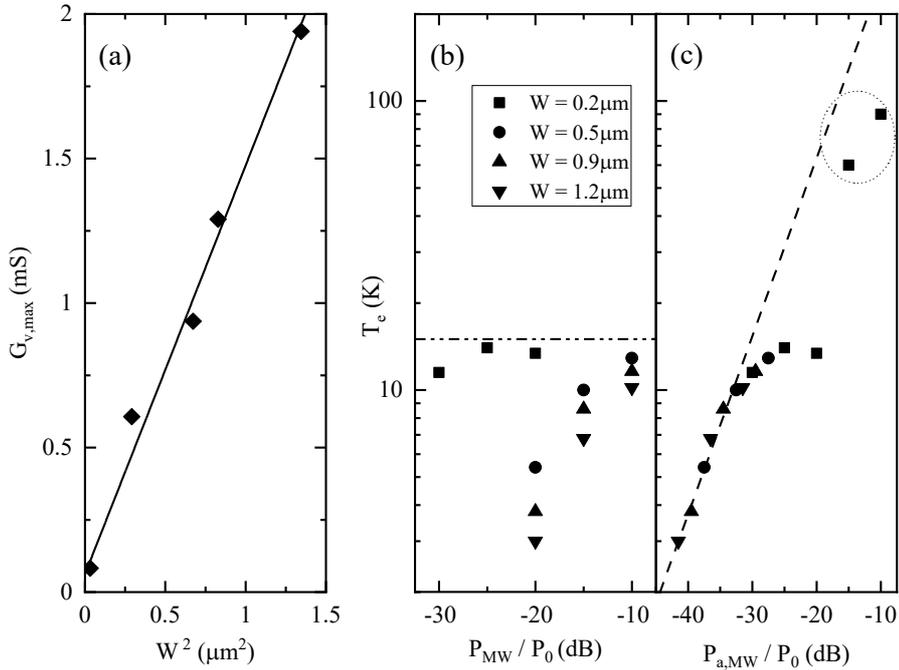


FIG. 3. (a) Maximum photoconductance of resistance minima $G_{v,max}$ is approximately proportional to W^2 , which is a clear indicator of viscous charge transport. (b) The relation between T_e at resistance minima and MW power is shown for four different QPCs (QPC 2d, $W = 0.2\mu m$; QPC 1b, $W = 0.5\mu m$; QPC 1b, $W =$

0.9 μm ; QPC 1a, $W = 1.2\mu m$). Since photo-induced resistance of a QPC may have several minima, we plot the average T_e of two prominent symmetric minima of each trace. Saturation of T_e due to phonon scattering is marked with dash-dot line. Subfigure (c) shows the result after $P_{a,MW}$ of all QPCs is changed to be the same as that of QPC 2d. Power law assumption of T_e and P_{MW} is shown as the dash line. T_e estimated in diffusive regime qualitatively favors the trend of T_e extracted in superballistic model.

In diffusive regime decided by phonon scattering, we can also estimate an approximate value of T_e . R_{QPC} was calculated from ballistic to diffusive transport regime [37]. It is proved that $R_{QPC} = R_b + R_d$ and Drude resistance

$$R_d = \frac{h}{2e^2} \frac{2}{\sqrt{2\pi n} l_0} \frac{L}{W}, \quad (5)$$

where L is QPC length, which is about 1.2 μm for our samples. Given complicated scattering mechanism in GaAs QW, e. g. acoustic and optic phonon scatterings, we can roughly estimate the relation between l_0 and T_e [38]. Then we obtain the estimated T_e in diffusive regime from resistance peaks (Fig.3(c)). The estimated T_e is lower than the extrapolated value in superballistic model, indicating clear enhancement of thermal conductance induced by electron-phonon coupling. When MW power is strong enough and huge resistance peaks appear ($P_{MW}/P_0 > 0dB$), mean free path $l_0 \ll L$ and T_e could be even higher than 100K. This fact interprets why EMP-induced resistance oscillation are so robust against high temperature.

Discussion. - Up till now, we have confirmed that the strange resistance oscillation at $\omega > \omega_c$ is induced by EMPs and, due to MW heating (just like micro-oven) at interference construction point of EMPs, superballistic effect result in positive photoconductance before negative photoconductance of EMPs appears. The strangest thing in our experiment is still unclear. That is the distinction between the region at $\omega > \omega_c$ and the one at $\omega < \omega_c$.

In paper [23], we attributed the distinction to different MW absorption rate. Photoconductance maxima appear when MW absorption rate reaches maxima and high T_e results in superballistic/diffusive transport. When MW power is high, hot electrons passing through QPC inject into cold bulk 2DEG.

In a previous MW absorption experiment [39], only cyclotron resonance can make 2DEG absorb more MW, but what happens if it is a narrow constriction like QPC? The cyclotron radius is $r_c = 0.76\mu m/B(kG)$, which is of the same order of QPC width W . We should notice in Fig.2 that the resistance minima or huge peaks (apart from cyclotron resonance) only appear when $r_c > W$. It seems that frequent collisions of electrons on the QPC boundary may magnify MW absorption rate and thus the EMP-induced resistance oscillation. This is because collisions of electrons can be related with photons. Lower conductance induced by collisions may also bring about high MW absorption rate.

Existence of MIRO and ZRS in the bulk 2DEG further complicates the problem. In our ultrahigh-mobility samples, high-quality MIRO and robust ZRS exist in the bulk connected by the QPC (Fig.4). Thus, it's interesting to discuss the interaction among bulk electrons and narrow constriction. When cyclotron orbits and current domains form in MIRO or ZRS and QPC width W is smaller than their size, cyclotron orbits or current domains in QPC are completely destroyed. Electrons injected from source to drain break the equilibrium of MIRO/ZRS and result in negative resistance of MIRO [33]. Electrons transforming between MIRO/ZRS and QPC modes may absorb huge amount of MW. According to Fig.4, resistance minima/maxima of R_L happen exactly when bulk electrons are in the regions of MIRO minima or ZRS. Once MIRO/ZRS is destroyed, electrons must consecutively absorb photons in order to maintain stability. This evidence unambiguously substantiates the relation between MW absorption and breaking of cyclotron orbits or current domains in the QPC region. Additionally, low conductance induced by MIRO minima/ZRS also contributes to high MW absorption rate.

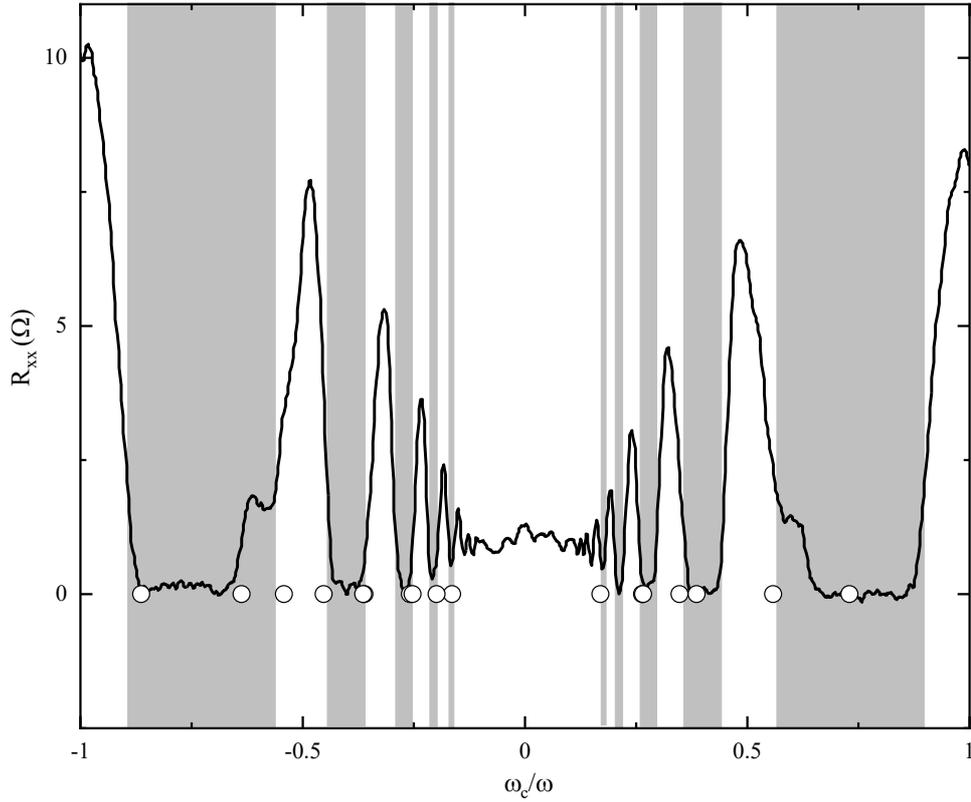


FIG. 4. MIRO in the bulk of ultrahigh-mobility 2DEG is demonstrated together with EMP-induced resistance minima/maxima marked by hollow circles and MIRO minima/ZRS are marked with grey background. We see that MW absorption rate maxima points tend to appear in the region of MIRO minima/ZRS. This is probably due to the fact that low conductance results in high MW absorption rate, especially when cyclotron orbits or current domains are destroyed in QPC region.

Conclusion. - We find out a novel EMP-induced resistance oscillation of QPC under MW radiation. The positive-to-negative photoconductance transformation is proved to be related to superballistic flow of electrons through QPC. The distinction between the regions $\omega > \omega_c$ and $\omega < \omega_c$ is attributed to different absorption rate of MW radiation. Violent absorption occurs when cyclotron orbits or current domains are destroyed in QPC region.

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References

- [1] D. A. Bandurin, I. Torre, R. K. Kumar, M. B. Shalom, A. Tomadin, A. Principi, G. H. Auton, E. Khestanova, K. S. Novoselov, I. V. Grigorieva, et al., “Negative local resistance caused by viscous electron backflow in graphene”, *Science* **351**, 1055 (2016).
- [2] R. K. Kumar, D. A. Bandurin, F. M. D. Pellegrino, Y. Cao, A. Principi, H. Guo, G. H. Auton, M. B. Shalom, L. A. Ponomarenko, G. Falkovich, et al., “Superballistic flow of viscous electron fluid through graphene constrictions”, *Nat. Phys.* **13**, 1182 (2017).
- [3] G. M. Gusev, A. D. Levin, E. V. Levinson, and A. K. Bakarov, “Viscous electron flow in mesoscopic two-dimensional electron gas”, *AIP Adv.* **8**, 025318 (2018).
- [4] A. D. Levin, G. M. Gusev, E. V. Levinson, Z. D. Kvon, and A. K. Bakarov, “Vorticity-induced negative nonlocal resistance in a viscous two-dimensional electron system”, *Phys. Rev. B* **97**, 245308 (2018).
- [5] G. M. Gusev, A. D. Levin, E. V. Levinson, and A. K. Bakarov, “Viscous transport and Hall viscosity in a two-dimensional electron system”, *Phys. Rev. B* **98**, 161303(R) (2018).
- [6] B. A. Braem, et.al., “Scanning gate microscopy in a viscous electron fluid”, *Phys. Rev. B* **98**, 241304(R) (2018).
- [7] A. C. Keser, et. al., “Geometric control of universal hydrodynamic flow in a two-dimensional electron fluid”, *Phys. Rev. X* **11**, 031030 (2021).
- [8] A. Gupta, J. J. Heremans, G. Kataria, M. Chandra, S. Fallahi, G. C. Gardner and M. J. Manfra, “Hydrodynamic and ballistic transport over large length scales in GaAs/AlGaAs”, *Phys. Rev. Lett.* **126**, 076803 (2021).

- [9] X. Wang, et. al., “Hydrodynamic charge transport in GaAs/AlGaAs ultrahigh-mobility two-dimensional electron gas”, *Phys. Rev. B* **106**, L241302 (2022)
- [10] Y. Dai, R. R. Du, L. N. Pfeiffer, and K. W. West, “Observation of a cyclotron harmonic spike in microwave-induced resistances in ultraclean GaAs/AlGaAs quantum wells”, *Phys. Rev. Lett.* **105**, 246802 (2010).
- [11] Y. V. Sharvin, “A possible method for studying Fermi surfaces”, *Sov. Phys. JETP* **21**, 655–656 (1965).
- [12] C. W. J. Beenakker & H. van Houten, “Quantum transport in semiconductor nanostructures”, *Solid State Phys.* **44**, 1–228 (1991).
- [13] M. A. Zudov, R. R. Du, J. A. Simmons, and J. L. Reno, “Shubnikov–de Haas-like oscillations in millimeterwave photoconductivity in a high-mobility two-dimensional electron gas”, *Phys. Rev. B* **64**, 201311(R) (2001).
- [14] P. D. Ye, L. W. Engel, D. C. Tsui, J. A. Simmons, J. R. Wendt, G. A. Vawter, and J. L. Reno, “Giant microwave photoresistance of two-dimensional electron gas”, *Appl. Phys. Lett.* **79**, 2193 (2001).
- [15] R. G. Mani, J. H. Smet, K. von Klitzing, V. Narayanamurti, W. B. Johnson, and V. Umansky, “Zero-resistance states induced by electromagnetic-wave excitation in GaAs/AlGaAs heterostructures”, *Nature* **420**, 646 (2002).
- [16] M. A. Zudov, R. R. Du, L. N. Pfeiffer, and K. W. West, “Evidence for a New Dissipationless Effect in 2D Electronic Transport”, *Phys. Rev. Lett.* **90**, 046807 (2003).
- [17] P. S. Alekseev, “Negative magnetoresistance in viscous flow of two-dimensional electrons”, *Phys. Rev. Lett.* **117**, 166601 (2016).
- [18] P. S. Alekseev, “Magnetic resonance in a high-frequency flow of a two-dimensional viscous electron fluid”, *Phys. Rev. B* **98**, 165440 (2018).
- [19] P. S. Alekseev and A. P. Alekseeva, “Transverse magnetosonic waves and viscoelastic resonance in a two-dimensional highly viscous electron fluid”, *Phys. Rev. Lett.* **123**, 236801 (2019).
- [20] P. S. Alekseev, “Magnetosonic waves in a two-dimensional electron Fermi liquid”, *Semiconductors* **53**, 1367 (2019).
- [21] P. S. Alekseev and A. P. Dmitriev, “Viscosity of two-dimensional electrons”, *Phys. Rev. B* **102**, 241409(R) (2020).

- [22] P. S. Alekseev and A. P. Alekseeva, “Microwave-induced resistance oscillations in highly viscous electron fluid”, arXiv preprint arXiv:2105.01035v2.
- [23] Xinghao Wang, Wenfeng Zhang, Rui-Rui Du, L. N. Pfeiffer, K. W. Baldwin, and K. W. West, “Aharonov-Born oscillation and Microwave-induced edge-magnetoplasmon modes enhanced by quantum point contact”, preprint (2024).
- [24] I. V. Kukushkin, et. al., “New Type of B-Periodic Magneto-Oscillations in a Two-Dimensional Electron System Induced by Microwave Irradiation”, *Phys. Rev. Lett.* **92**, 236803 (2004).
- [25] I. V. Kukushkin, et. al., “Miniature quantum-well microwave spectrometer operating at liquid-nitrogen temperatures”, *Appl. Phys. Lett.* **86**, 044101 (2005).
- [26] K. Stone, et.al., “Photovoltaic oscillations due to edge-magnetoplasmon modes in a very high-mobility two-dimensional electron gas”, *Phys. Rev. B* **76**, 153306 (2007).
- [27] A. D. Levin, et. al., “Giant microwave-induced B -periodic magnetoresistance oscillations in a two-dimensional electron gas with a bridged-gate tunnel point contact”, *Phys. Rev. B* **95**, 081408(R) (2017).
- [28] R. L. Willett, L. N. Pfeiffer, and K. W. West, “Evidence for Current-Flow Anomalies in the Irradiated 2D Electron System at Small Magnetic Fields”, *Phys. Rev. Lett.* **93**, 026804 (2004).
- [29] A. V. Andreev, I. L. Aleiner, and A. J. Millis, “Dynamical Symmetry Breaking as the Origin of the Zero-dc-Resistance State in an ac-Driven System”, *Phys. Rev. Lett.* **91**, 056803 (2003).
- [30] A. Auerbach, I. Finkler, B. I. Halperin, and A. Yacoby, “Steady States of a Microwave-Irradiated Quantum-Hall Gas”, *Phys. Rev. Lett.* **94**, 196801 (2005).
- [31] Finkler, I. G., and B. I. Halperin, “Microwave-induced zero-resistance states are not necessarily static”, *Phys. Rev. B* **79**, 085315 (2009).
- [32] I. A. Dmitriev, A. D. Mirlin, D. G. Polyakov, M. A. Zudov, “Nonequilibrium phenomena in high Landau levels”, *Rev. Mod. Phys.* **84**, 1709 (2012)
- [33] Supplementary materials.
- [34] M. Buttiker, “Four-terminal phase-coherent conductance”, *Phys. Rev. Lett.* **57**(14):1761-1764, (1986).

- [35] V. T. Renard, et. al., “Boundary-Mediated Electron-Electron Interactions in Quantum Point Contacts”, *Phys. Rev. Lett.* **100**, 186801 (2008).
- [36] H. Guo, et. al., “Higher-than-ballistic conduction of viscous electron flows”, *Proc. Natl Acad. Sci. USA* **114**, 3068–3073 (2017).
- [37] M. J. M. de Jong, “Transition from Sharvin to Drude resistance in high-mobility wires”, *Phys. Rev. B* **49**, 7778–7781 (1994).
- [38] L. Pfeiffer, et. al., “The role of MBE in recent quantum Hall effect physics discoveries”, *Physica E* **20**, 57–64 (2003).
- [39] S. A. Studenikin, M. Potemski, A. Sachrajda, M. Hilke, L. N. Pfeiffer and K. W. West, “Microwave-induced resistance oscillations on a high-mobility two-dimensional electron gas: Exact waveform, absorption/reflection and temperature damping”, *Phys. Rev. B* **71**, 245313 (2005).